

### Product Summary

| Part #  | $V_{DS}$ | $R_{DS(on).typ}$<br>(@ $V_{GS}=10V$ ) | $R_{DS(on).typ}$<br>(@ $V_{GS}=4.5V$ ) | $I_D$ |
|---------|----------|---------------------------------------|--|-------|
| EFM2308 | 60V      | 70m $\Omega$                          | 86m $\Omega$                           | 3.5A  |

### Features

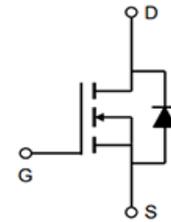
- Low  $R_{DS(on)}$  @ $V_{GS}=10V$
- 5V Logic Level Control
- N Channel SOT23 Package
- Pb-Free, RoHS Compliant

### Application

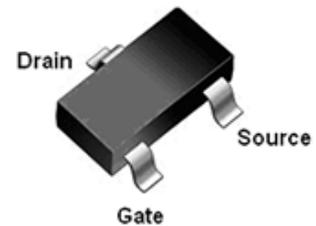
- Load Switch
- Battery switch
- DC/DC Converter

### Ordering Information:

|                           |           |
|---------------------------|-----------|
| Part NO.                  | EFM2308   |
| Marking                   | L8***     |
| Packing Information       | REEL TAPE |
| Basic ordering unit (pcs) | 3000      |



N-Channel MOSFET



SOT- 23



### Absolute Maximum Ratings ( $T_C=25^\circ C$ )

| Parameter  | Symbol         | Limit      | Unit       |
|--|----------------|------------|------------|
| Drain-Source Voltage                             | $V_{DS}$       | 60         | V          |
| Gate-Source Voltage                              | $V_{GS}$       | $\pm 20$   | V          |
| Drain Current-Continuous                         | $I_D$          | 3.5        | A          |
| Drain Current-Pulsed <sup>(Note 1)</sup>         | $I_{DM}$       | 15.2       | A          |
| Maximum Power Dissipation                        | $P_D$          | 1.56       | W          |
| Operating Junction and Storage Temperature Range | $T_J, T_{STG}$ | -55 To 150 | $^\circ C$ |

### Thermal Characteristic

|   |                 |    |              |
|---|-----------------|----|--------------|
| Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup> | $R_{\theta JA}$ | 80 | $^\circ C/W$ |
|---|-----------------|----|--------------|

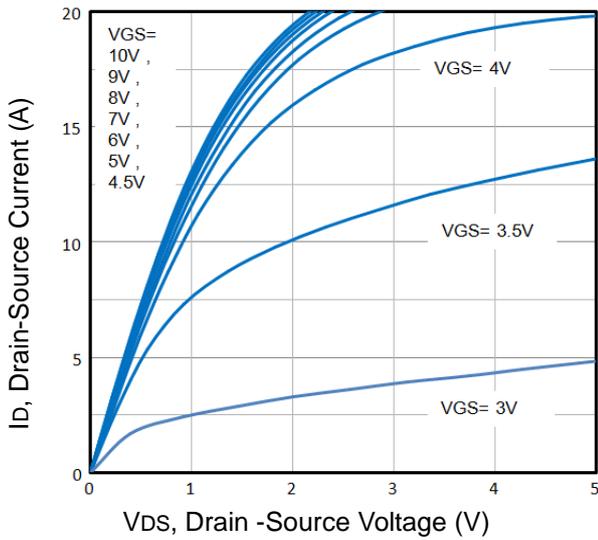
• Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)

| Parameter                                 | Symbol              | Condition   | Min | Typ  | Max  | Unit |
|---|---------------------|---|-----|------|------|------|
| <b>Off Characteristics</b>                |                     |   |     |      |      |      |
| Drain-Source Breakdown Voltage            | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250uA   | 60  | --   | --   | V    |
| Zero Gate Voltage Drain Current           | I <sub>DSS</sub>    | V <sub>DS</sub> =60V V <sub>GS</sub> =0V  | --  | --   | 1    | μA   |
| Gate-Body Leakage Current                 | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V V <sub>DS</sub> =0V   | --  | --   | ±100 | nA   |
| <b>On Characteristics</b> (Note 3)        |                     |   |     |      |      |      |
| Gate Threshold Voltage                    | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> I <sub>D</sub> =250uA                                | 1.0 | 1.5  | 3.0  | V    |
| Drain-Source On-State Resistance          | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V I <sub>D</sub> =3.5A   | --  | 70   | 85   | mΩ   |
|   |                     | V <sub>GS</sub> =4.5V I <sub>D</sub> =3A  | --  | 86   | 110  | mΩ   |
| <b>Dynamic Characteristics</b> (Note4)    |                     |   |     |      |      |      |
| Input Capacitance                         | C <sub>iss</sub>    | V <sub>DS</sub> =30V V <sub>GS</sub> =0V<br>F=1.0MHz                                  | --  | 362  | --   | PF   |
| Output Capacitance                        | C <sub>oss</sub>    |   | --  | 23   | --   | PF   |
| Reverse Transfer Capacitance              | C <sub>rss</sub>    |   | --  | 16   | --   | PF   |
| Gate Resistance                           | R <sub>g</sub>      | F=1.0MHz  | --  | 9    | --   | Ω    |
| <b>Switching Characteristics</b> (Note 4) |                     |   |     |      |      |      |
| Turn-on Delay Time                        | t <sub>d(on)</sub>  | V <sub>DD</sub> =30V I <sub>D</sub> =1A<br>V <sub>GS</sub> =10V R <sub>G</sub> =3.3Ω, | --  | 3.4  | --   | nS   |
| Turn-on Rise Time                         | t <sub>r</sub>      |   | --  | 5.8  | --   | nS   |
| Turn-Off Delay Time                       | t <sub>d(off)</sub> |   | --  | 21   | --   | nS   |
| Turn-Off Fall Time                        | t <sub>f</sub>      |   | --  | 4.6  | --   | nS   |
| Total Gate Charge                         | Q <sub>g</sub>      | V <sub>DS</sub> =30V I <sub>D</sub> =4A<br>V <sub>GS</sub> =10V                       | --  | 6.9  | --   | nC   |
| Gate-Source Charge                        | Q <sub>gs</sub>     |   | --  | 0.9  | --   | nC   |
| Gate-Drain Charge                         | Q <sub>gd</sub>     |   | --  | 1.8  | --   | nC   |
| <b>Drain-Source Diode Characteristics</b> |                     |   |     |      |      |      |
| Diode Forward Voltage (Note 3)            | V <sub>SD</sub>     | V <sub>GS</sub> =0V I <sub>S</sub> =2A  | --  | 0.79 | 1.2  | V    |
| Diode Forward Current (Note 2)            | I <sub>S</sub>      |   | --  | --   | 2    | A    |

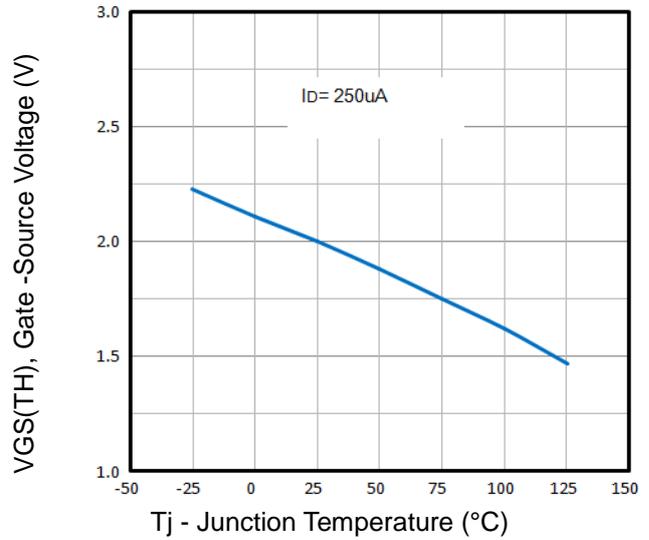
Notes:

- ① Pulse width limited by maximum allowable junction temperature
- ② Pulse test ; Pulse width ≤ 300μs, duty cycle ≤ 2%.

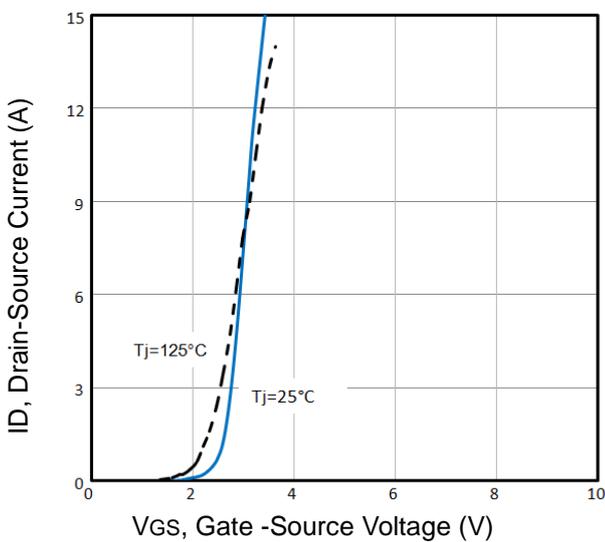
• Typical Characteristics



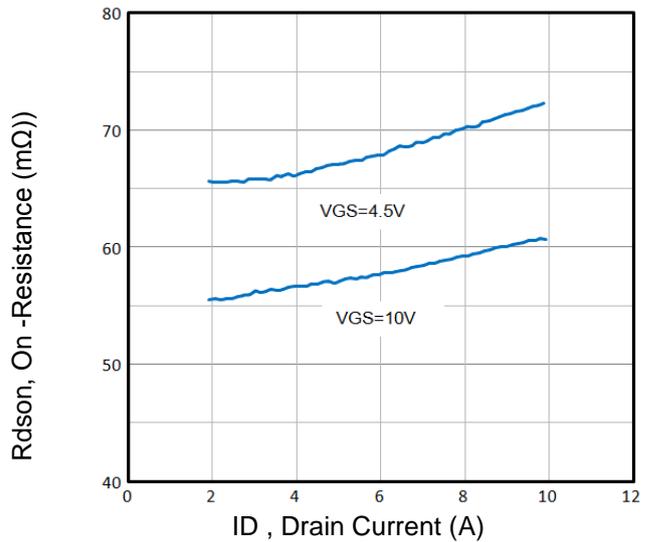
**Fig1.** Typical Output Characteristics



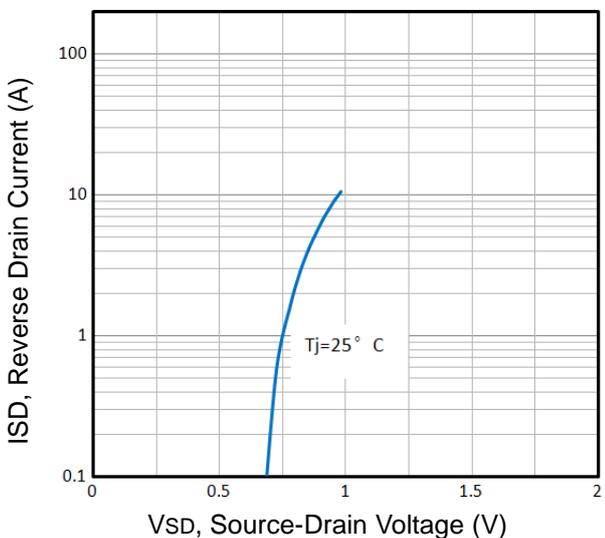
**Fig2.** VGS(TH) Voltage Vs. Temperature



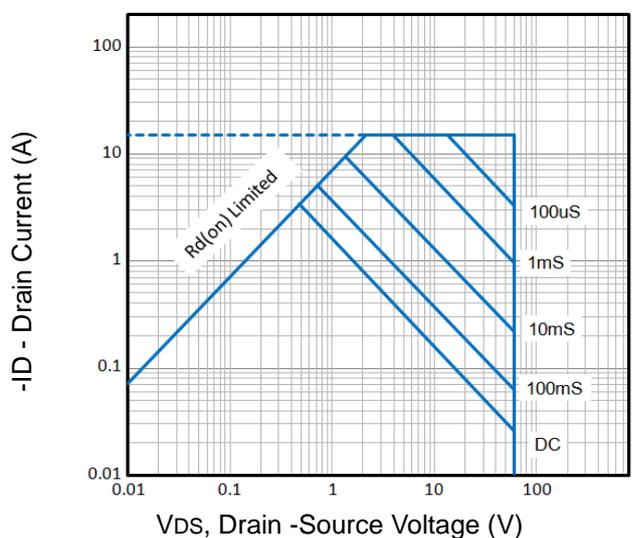
**Fig3.** Typical Transfer Characteristics



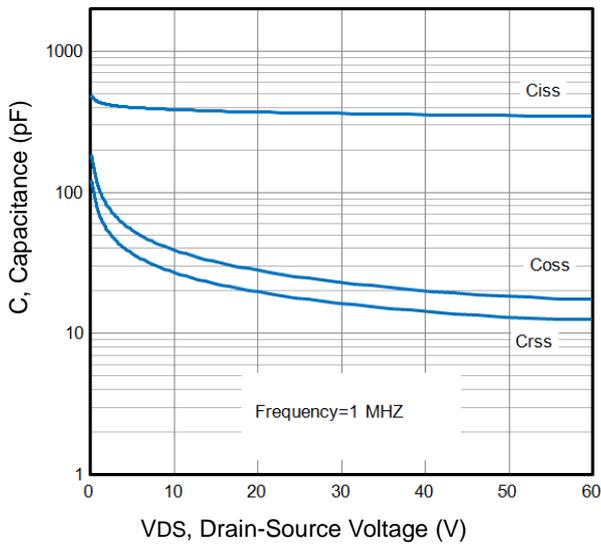
**Fig4.** On-Resistance vs. Drain Current and Gate



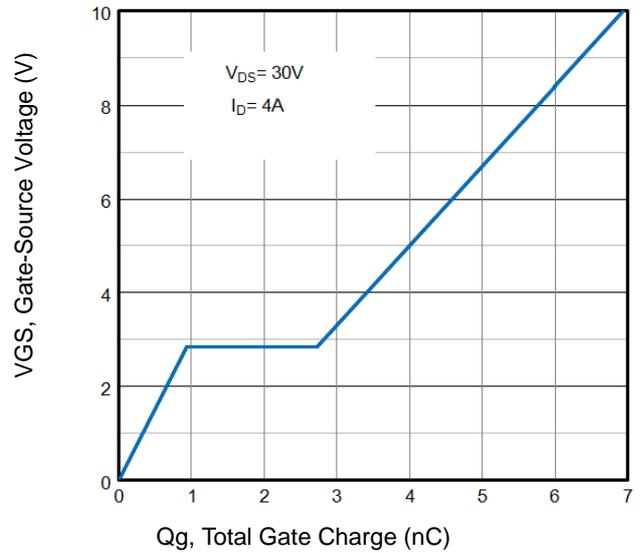
**Fig5.** Typical Source-Drain Diode Forward Voltage



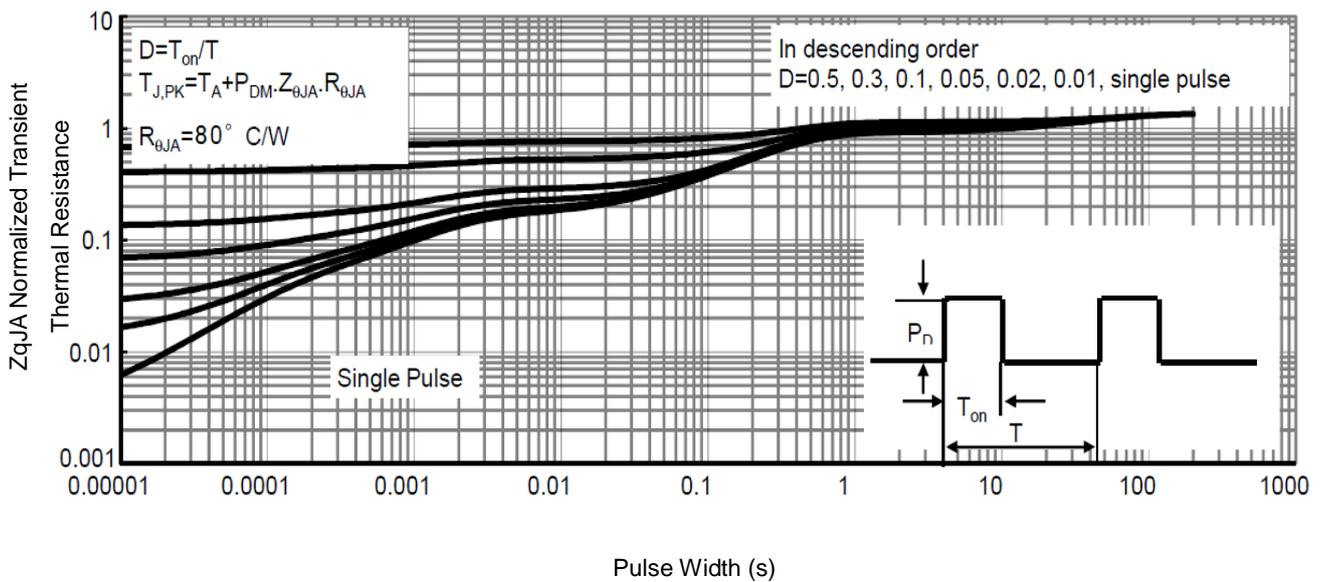
**Fig6.** Maximum Safe Operating Area



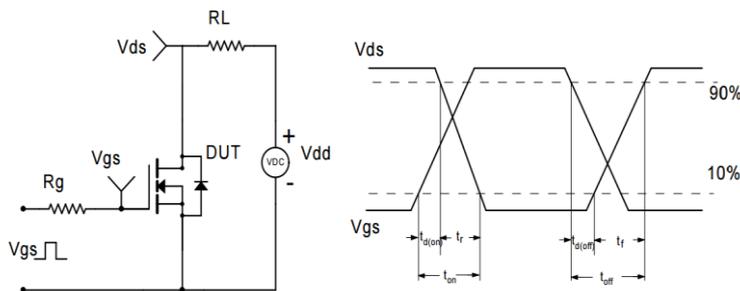
**Fig7.** Typical Capacitance Vs. Drain-Source Voltage



**Fig8.** Typical Gate Charge Vs. Gate-Source Voltage

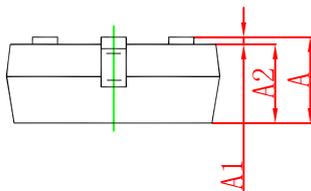
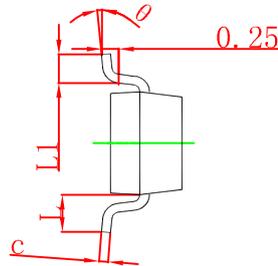
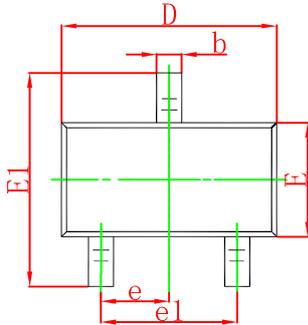


**Fig9.** Normalized Maximum Transient Thermal Impedance

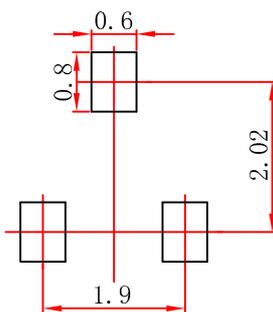


**Fig10.** Switching Time Test Circuit and waveforms

## SOT-23 Package Outline Dimensions



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | 0.900                     | 1.150 | 0.035                | 0.045 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 0.900                     | 1.050 | 0.035                | 0.041 |
| b      | 0.300                     | 0.500 | 0.012                | 0.020 |
| c      | 0.080                     | 0.150 | 0.003                | 0.006 |
| D      | 2.800                     | 3.000 | 0.110                | 0.118 |
| E      | 1.200                     | 1.400 | 0.047                | 0.055 |
| E1     | 2.250                     | 2.550 | 0.089                | 0.100 |
| e      | 0.950 TYP                 |       | 0.037 TYP            |       |
| e1     | 1.800                     | 2.000 | 0.071                | 0.079 |
| L      | 0.550 REF                 |       | 0.022 REF            |       |
| L1     | 0.300                     | 0.500 | 0.012                | 0.020 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |



**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.